Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)
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P1 98.2



IANNEL MOS FIELD EFFECT POWER TRANSISTORS

2SK1059, 2SK1059-Z



The 2SK1059, 2SK1059-Z are N-Channel MOS Field Effect Power Transistor designed for solenoid, motor and lamp driver.

FEATURES

- 4 V Gate Drive Logic level —
- Low R_{DS(on)}
- No Second Breakdown
- Designed for Hybrid Integrated Circuits

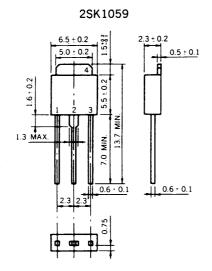
ABSOLUTE MAXIMUM RATINGS

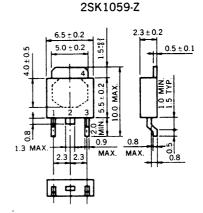
Maximum Temp			
Storage Te	emperature	5 to +1	50 °C
Junction 7	Temperature 150	°C Max	imum
Maximum Powe	r Dissipations		
Total Pow	er Dissipation*	2.0	W
Total Pow	- 20	W	
Maximum Volta	iges and Currents (T _a = 25 °C)		
V_{DSS}	Drain to Source Voltage	60	٧
V_{GSS}	Gate to Source Voltage	±20	٧
I _{D(DC)}	Drain Current (DC)	±5	Α
I _{D(pulse)}	Drain Current (pulse)**.*	±20	Α
	red on ceramic substrate of 7.5 cm ² x 0).7 mm	
** T _c = 2 *** PW ≤	25 °C 10 µs. Duty Cycle ≤ 1 %		

ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

SYMBOL	CHARACTERISTIC	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
R _{DS} (on)	Drain to Source On-State Resistance		0.1	0.135	Ω	V _{GS} = 10 V, I _D = 3 A
R _{DS} (on)	Drain to Source On-State Resistance		0.15	0.22	Ω	V _{GS} = 4 V, I _D = 3 A
V _{GS(off)}	Gate to Source Cutoff Voltage	1.0		2.5	٧	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
yfs	Forward Transfer Admittance	4.0			s	$V_{DS} = 10 \text{ V}, I_D = 3 \text{ A}$
IDSS	Drain Leakage Current			10	μΑ	$V_{DS} = 60 \text{ V}, V_{GS} = 0$
IGSS	Gate to Source Leakage Current			±100	nA	$V_{GS} = \pm 20 \text{ V, } V_{DS} = 0$
Ciss	Input Capacitance		900		pF	V _{DS} = 10 V
Coss			350 100		pF	V _{GS} = 0
C _{rss}					pF	f = 1 MHz
^t d(on)	Turn-On Delay Time		10		ns	
t _r Rise Time			40 ns 110 ns		ns	I_D = 3 A, $V_{DD} = 10 \text{ V}$ R_L = 17 Ω R_{in} = 10 Ω
^t d(off)	ff) Turn-Off Delay Time				ns	
tf	Fall Time		30		ns	

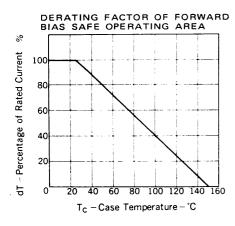
PACKAGE DIMENSIONS (Unit: mm)

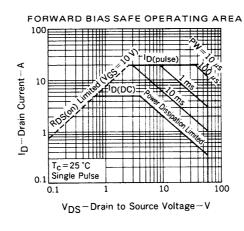


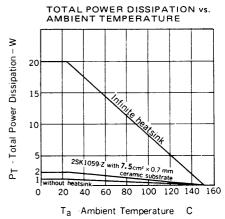


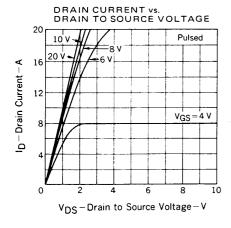
- 1. Gate
- Drain
 Source
- 4. Drain (Fin)

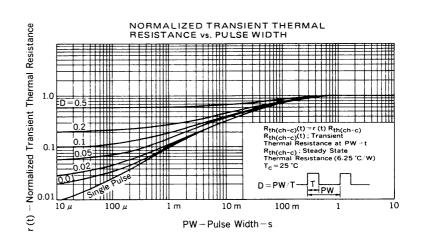
TYPICAL CHARACTERISTICS (Ta = 25 °C)

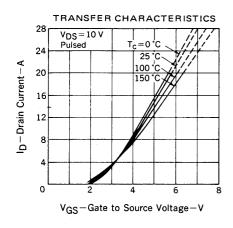


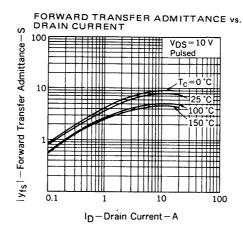


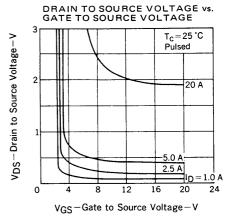


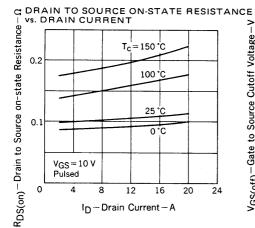


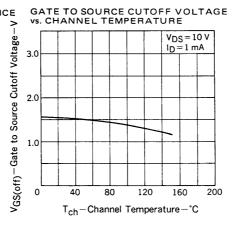


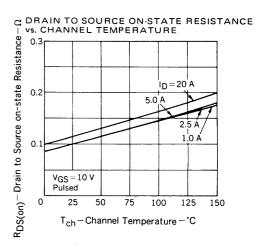


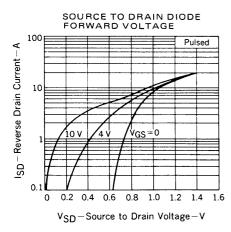


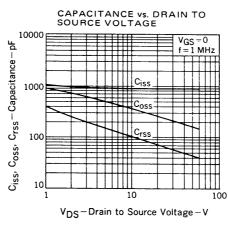


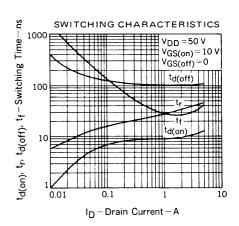


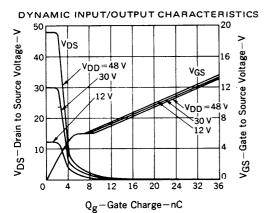




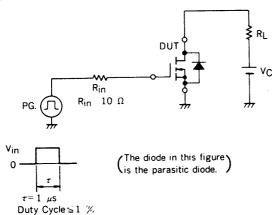


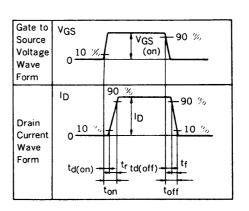






SWITCHING TIME TEST CIRCUIT





GATE CHARGE TEST CIRCUIT

